阅读申明

- 1.本站收集的数据手册和产品资料都来自互联网,版权归原作者所有。如读者和版权方有任何异议请及时告之,我们将妥善解决。
- 2.本站提供的中文数据手册是英文数据手册的中文翻译,其目的是协助用户阅读,该译文无法自动跟随原稿更新,同时也可能存在翻译上的不当。建议读者以英文原稿为参考以便获得更精准的信息。
- 3.本站提供的产品资料,来自厂商的技术支持或者使用者的心得体会等,其内容可能存在描 叙上的差异,建议读者做出适当判断。
- 4.如需与我们联系,请发邮件到marketing@iczoom.com,主题请标有"数据手册"字样。

Read Statement

- 1. The datasheets and other product information on the site are all from network reference or other public materials, and the copyright belongs to the original author and original published source. If readers and copyright owners have any objections, please contact us and we will deal with it in a timely manner.
- 2. The Chinese datasheets provided on the website is a Chinese translation of the English datasheets. Its purpose is for reader's learning exchange only and do not involve commercial purposes. The translation cannot be automatically updated with the original manuscript, and there may also be improper translations. Readers are advised to use the English manuscript as a reference for more accurate information.
- 3. All product information provided on the website refer to solutions from manufacturers' technical support or users the contents may have differences in description, and readers are advised to take the original article as the standard.
- 4. If you have any questions, please contact us at marketing@iczoom.com and mark the subject with "Datasheets" .



KA1H0165RN/KA1H0165R

Fairchild Power Switch(FPS)

Features

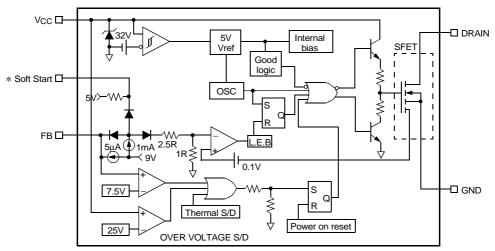
- Precision Fixed Operating Frequency (100kHz)
- Pulse by Pulse Over Current Limiting
- Over Load Protection
- Over Voltage Protection (Min. 23V)
- Internal Thermal Shutdown Function
- Under Voltage Lockout
- Internal High Voltage Sense FET
- · Auto Restart Mode

Description

The Fairchild Power Switch(FPS) product family is specially designed for an off line SMPS with minimal external components. The Fairchild Power Switch(FPS) consist of high voltage power SenseFET and current mode PWM controller IC. PWM controller features integrated fixed oscillator, under voltage lock out, leading edge blanking, optimized gate turn-on/turn-off driver, thermal shut down protection, over voltage protection, temperature compensated precision current sources for loop compensation and fault protection circuit compared to discrete MOSFET and controller or RCC switching converter solution The Fairchild Power Switch(FPS) can reduce total component count, design size, weight and at the same time increase & efficiency, productivity, and system reliability. It has a basic platform well suited for cost effective design in either a flyback converter or a forward converter.

8-DIP	TO-220F-4L
1 1.6.7.8. Drain 2. GND 3. VCC 4. F/B 5. S/S	1 1. GND 2. Drain 3. VCC 4. F/B

Internal Block Diagram



Absolute Maximum Ratings

Parameter	Symbol	Value	Unit
Maximum Drain Voltage (1)	V _{D,MAX}	650	V
Drain-Gate Voltage (RGS=1MΩ)	VDGR	650	V
Gate-Source (GND) Voltage	VGS	±30	V
Drain Current Pulsed (2)	IDM	4.0	ADC
Single Pulsed Avalanche Energy (3)	Eas	95	mJ
Continuous Drain Current (T _C =25°C)	ΙD	1.0	ADC
Continuous Drain Current (Tc=100°C)	ID	0.7	ADC
Maximum Supply Voltage	VCC,MAX	30	V
Input Voltage Range	VFB	-0.3 to VSD	V
Total Power Dissipation	PD	40	W
	Darting	0.32	W/°C
Operating Ambient Temperature	TA	-25 to +85	°C
Storage Temperature	T _{STG}	-55 to +150	°C

Notes:

- 1. $T_j = 25^{\circ}C$ to $150^{\circ}C$
- 2. Repetitive rating: Pulse width limited by maximum junction temperature
- 3. L = 80mH, V_{DD} = 50V, R_G = 27 Ω , starting T_j = 25°C

Electrical Characteristics (SFET Part)

(Ta=25°C unless otherwise specified)

Parameter	Symbol	Condition	Min.	Тур.	Max.	Unit
Drain-Source Breakdown Voltage	BVDSS	VGS=0V, ID=50μA	650	-	-	V
Zero Gate Voltage Drain Current	IDSS	VDS=Max., Rating, VGS=0V	-	-	50	μΑ
		V _{DS} =0.8Max., Rating, V _{GS} =0V, T _C =125°C	-	-	200	μΑ
Static Drain-Source on Resistance (Note)	RDS(ON)	VGS=10V, ID=0.5A	-	8	10	Ω
Forward Transconductance (Note)	gfs	V _{DS} =50V, I _D =0.5A	0.5	-	-	S
Input Capacitance	Ciss	\\ 0\\ \\ 0\\	-	250	-	pF
Output Capacitance	Coss	VGS=0V, VDS=25V, f=1MHz	-	25	-	
Reverse Transfer Capacitance	Crss	1-11/11/2	-	10	-	
Turn on Delay Time	td(on)	VDD=0.5B VDSS, ID=1.0A	-	12	-	
Rise Time	tr	(MOSFET switching	-	4	-	nS
Turn off Delay Time	td(off)	time is essentially independent of	-	30	-	113
Fall Time	tf	operating temperature)	-	10	-	
Total Gate Charge (Gate-Source+Gate-Drain)	Qg	V _{GS} =10V, I _D =1.0A, V _{DS} =0.5B V _{DS} S (MOSFET	-	-	21	
Gate-Source Charge	Qgs	switching time is essentially independent of operating	-	3	-	nC
Gate-Drain (Miller) Charge	Qgd	temperature)	-	9	-	

Note:

1. Pulse test: Pulse width $\leq 300 \mu S$, duty cycle $\leq 2\%$

$$2. S = \frac{1}{R}$$

Electrical Characteristics (Control Part) (Continued)

(Ta=25°C unless otherwise specified)

Parameter	Symbol	Condition	Min.	Тур.	Max.	Unit	
UVLO SECTION							
Start Threshold Voltage	VSTART	-	14	15	16	V	
Stop Threshold Voltage	VSTOP	After turn on	9	10	11	V	
OSCILLATOR SECTION							
Initial Accuracy	Fosc	Ta=25°C	90	100	110	kHz	
Frequency Change With Temperature (2)	ΔΕ/ΔΤ	-25°C ≤ Ta ≤ +85°C	-	±5	±10	%	
Maximum Duty Cycle	Dmax	-	64	67	70	%	
FEEDBACK SECTION							
Feedback Source Current	IFB	Ta=25°C, 0V ≤ Vfb ≤ 3V	0.7	0.9	1.1	mA	
Shutdown Feedback Voltage	VsD	-	6.9	7.5	8.1	V	
Shutdown Delay Current	Idelay	Ta=25°C, 5V ≤ Vfb ≤ V _{SD}	4.0	5.0	6.0	μΑ	
SOFT START SECTION (KA1H0165RN)							
Soft Start Voltage	Vss	VFB=2V	4.7	5.0	5.3	V	
Soft Start Current	ISS	Sync & S/S=GND	0.8	1.0	1.2	mA	
REFERENCE SECTION							
Output Voltage ⁽¹⁾	Vref	Ta=25°C	4.80	5.00	5.20	V	
Temperature Stability (1)(2)	Vref/∆T	-25°C ≤ Ta ≤ +85°C	-	0.3	0.6	mV/°C	
CURRENT LIMIT(SELF-PROTECTION)SECTION							
Peak Current Limit	IOVER	Max. inductor current	0.53	0.6	0.67	Α	
PROTECTION SECTION							
Thermal Shutdown Temperature ⁽¹⁾	T _{SD}	-	140	160	-	°C	
Over Voltage Protection Voltage	VOVP	-	23	25	28	V	
TOTAL DEVICE SECTION							
Start-Up Current	ISTART	VCC=14V	0.1	0.3	0.4	mA	
Operating Supply Current (Control Part Only)	IOP	Ta=25°C	6	12	18	mA	
VCC Zener Voltage	Vz	ICC=20mA	30	32.5	35	V	

Note:

- 1. These parameters, although guaranteed, are not 100% tested in production
- 2. These parameters, although guaranteed, are tested in EDS (wafer test) process

Typical Performance Characteristics

(These characteristic graphs are normalized at Ta=25°C)

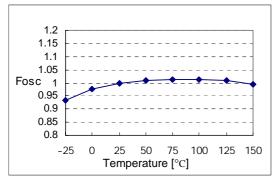


Figure 1. Operating Frequency

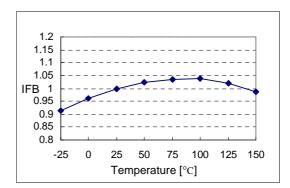


Figure 2. Feedback Source Current

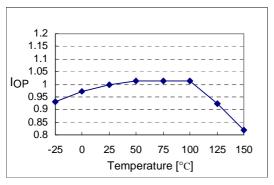


Figure 3. Operating Supply Current

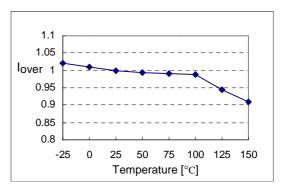


Figure 4. Peak Current Limit

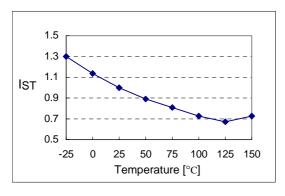


Figure 5. Start up Current

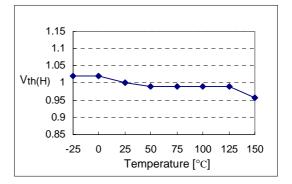


Figure 6. Start Threshold Voltage

Typical Performance Characteristics (Continued)

(These characteristic graphs are normalized at Ta=25°C)

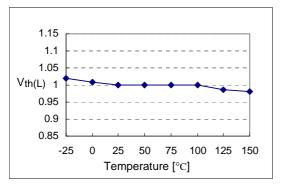


Figure 7. Stop Threshold Voltage

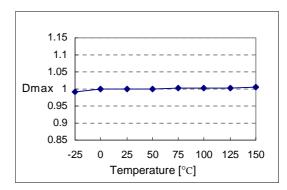


Figure 8. Maximum Duty Cycle

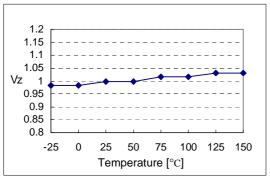


Figure 9. VCC Zener Voltage

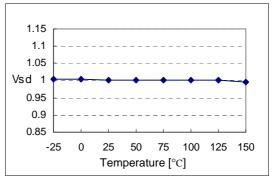


Figure 10. Shutdown Feedback Voltage

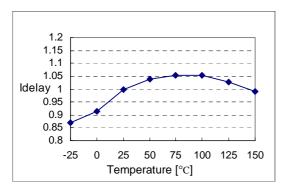


Figure 11. Shutdown Delay Current

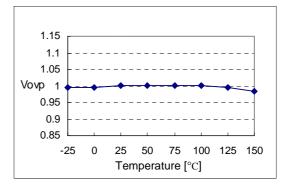


Figure 12. Over Voltage Protection

Typical Performance Characteristics (Continued)

(These characteristic grahps are normalized at Ta=25°C)

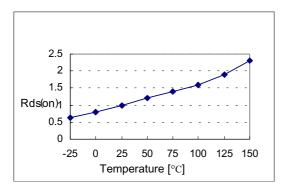
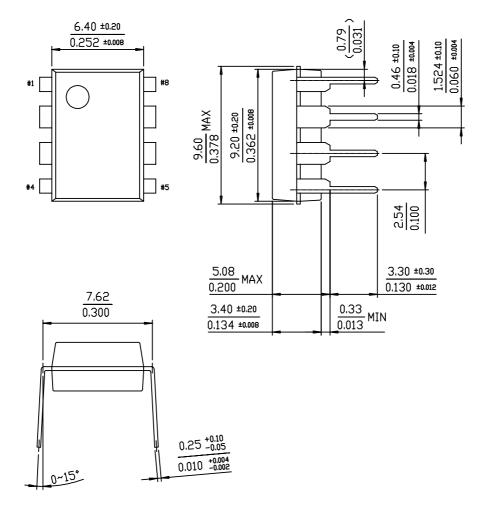


Figure 13. Static Drain-Source on Resistance

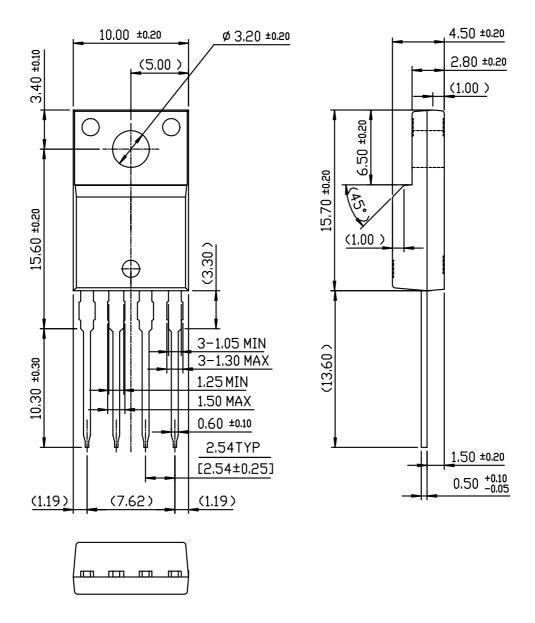
Package Dimensions

8-DIP



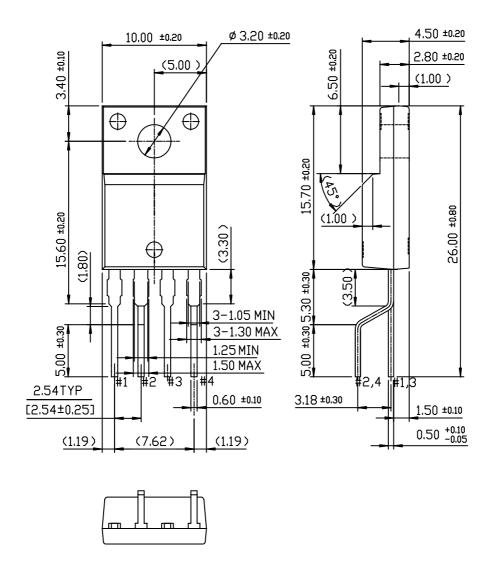
Package Dimensions (Continued)

TO-220F-4L



Package Dimensions (Continued)

TO-220F-4L(Forming)



Ordering Information

Product Number	Package	Rating	Operating Temperature
KA1H0165RN	8-DIP	650V, 1A	-25°C to +85°C
KA1H0165R-TU	TO-220F-4L	650V. 1A -25°C to +85	-25°C to +85°C
KA1H0165R-YDTU	10-220F-4L	050V, 1A	-25 C to +65 C

TU: Non Forming Type YDTU: Forming Type

DISCLAIMER

FAIRCHILD SEMICONDUCTOR RESERVES THE RIGHT TO MAKE CHANGES WITHOUT FURTHER NOTICE TO ANY PRODUCTS HEREIN TO IMPROVE RELIABILITY, FUNCTION OR DESIGN. FAIRCHILD DOES NOT ASSUME ANY LIABILITY ARISING OUT OF THE APPLICATION OR USE OF ANY PRODUCT OR CIRCUIT DESCRIBED HEREIN; NEITHER DOES IT CONVEY ANY LICENSE UNDER ITS PATENT RIGHTS, NOR THE RIGHTS OF OTHERS.

LIFE SUPPORT POLICY

FAIRCHILD'S PRODUCTS ARE NOT AUTHORIZED FOR USE AS CRITICAL COMPONENTS IN LIFE SUPPORT DEVICES OR SYSTEMS WITHOUT THE EXPRESS WRITTEN APPROVAL OF THE PRESIDENT OF FAIRCHILD SEMICONDUCTOR CORPORATION. As used herein:

- Life support devices or systems are devices or systems which, (a) are intended for surgical implant into the body, or (b) support or sustain life, and (c) whose failure to perform when properly used in accordance with instructions for use provided in the labeling, can be reasonably expected to result in a significant injury of the user.
- A critical component in any component of a life support device or system whose failure to perform can be reasonably expected to cause the failure of the life support device or system, or to affect its safety or effectiveness.

www.fairchildsemi.com